

NXP 500 mA resistorequipped transistors (RETs) PDTD and PDTB series

500 mA RETs for Automotive applications

Developed specifically for the automotive and industrial market, 500 mA RETs combine one or two resistors with a transistor to provide an optimal integrated solution for digital applications.

Key features

- ▶ Built-in bias resistors
- ▶ 500 mA collector current capability
- ▶ ± 10 % resistor tolerance
- ▶ 5 different resistor combinations (more on request)
- ▶ double versions in SOT457 (SC-74) on request

Key benefits

- ▶ lower handling and inventory costs
- ▶ reduced boardspace
- ▶ shorter assembly times
- reduced pick-and-place efforts
- simpler design process
- increased end product reliability due to fewer soldering points

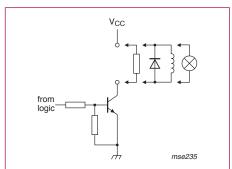
Key applications

- digital applications in automotive and industrial segments
- switching loads
- ▶ controlling IC inputs
- ▶ cost saving alternative for BC807/BC817 and their base resistors in digital applications

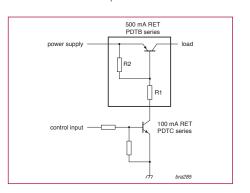




Application examples



RETs to switch loads up to 500 mA



Loadswitch using a 500 mA PNP RET



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Types and parametric data

Package					SOT23		SOT457 (SC-74)
Size (mm) P _{tot} (mW)					2.9 x 1.3 x 1.0 250		2.9 x 1.5 x 1.0 290
I _c (mA)	V _{CEO} (V)		R1 (kΩ)	R2 (kΩ)	R1 R2 MSE 185	R2 R2 MSE184	R1 R2 TR2 TR2 TR2 R1 R1 R2 Symbols
500	50	R1 = R2	1.0	1.0	PDTD113ET	PDTB113ET	
			2.2	2.2	PDTD123ET	PDTB123ET	
		R1 ≠ R2	1.0	10	PDTD113ZT	PDTB113ZT	PIMN31
			2.2	10	PDTD123YT	PDTB123YT	
		only R1	2.2	-	PDTD123TT	PDTB123TT	

Types in **bold**: samples included

Cross reference list

Device	NXP replacement
BCR503	PDTD123ET
BCR505	PDTD123YT
PCR521	PDTD113ET
BCR523	PDTD113ZT
BCR523U	PIMN31
BRC553	PDTB123ET
BCR571	PDTB113ET
BCR573	PDTB113ZT

Device	NXP replacement
DDTB113EC	PDTB113ET
DDTB113ZC	PDTB113ZT
DDTB123EC	PDTB123ET
DDTB123TC	PDTB123TT
DDTB123YC	PDTB123YT
DDTD113EC	PDTD113ET
DDTD113ZC	PDTD113ZT
DDTC123EC	PDTD123ET
DDTC123TC	PDTD123TT
DDTC123YC	PDTD123YT

NXP replacement
PBRN113ET
PBRP113ET
PBRN113ZT
PBRP113ZT
PBRN123ET
PBRP123ET
PBRN123YT
PBRP123YT



PDTD113ZT

R1 = 1, R2 = 10; NPN



PDTB113ZT

R1 = 1, R2 = 10; PNP



PDTD123TT

R1 = 2.2; NPN



PDTB123TT

R1 = 2.2; PNP



PIMN31

R1 = 1, R2 = 10; double NPN